

NP110N04PUK MOS FIELD EFFECT TRANSISTOR

The NP110N04PUK is N-channel MOS Field Effect Transistor designed for high current switching applications.

Features

- Super low on-state resistance $P_{max} = 1.4 \text{ mO MAX} (V_{max} = 1.4 \text{ mO MAX})$
- $R_{DS(on)} = 1.4 \text{ m}\Omega \text{ MAX. } (V_{GS} = 10 \text{ V}, I_D = 55 \text{ A})$ • Low C_{iss}: C_{iss} = 10500 pF TYP. (V_{DS} = 25 V)
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Pac	Package	
NP110N04PUK-E1-AY *1	Pure Sn (Tin)	Tape 800 p/reel	Taping (E1 type)	TO-263 (MP-25ZP)
NP110N04PUK-E2-AY *1			Taping (E2 type)	

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V _{GS} = 0 V)	VDSS	40	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) ($T_c = 25^{\circ}C$)	I _{D(DC)}	±110	A
Drain Current (pulse) * ^{1, 3}	I _{D(pulse)}	±440	A
Total Power Dissipation ($T_c = 25^{\circ}C$)	P _{T1}	348	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.8	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	–55 to 175	°C
Repetitive Avalanche Current *2, 3	lar	72	A
Repetitive Avalanche Energy *2, 3	EAR	518	mJ

Thermal Resistance

Channel to Case Thermal Resistance	Rth(ch-C)*3	0.43	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *3	83.3	°C/W

Notes: *1 T_C = 25°C, P_W \leq 10 μ s, Duty Cycle \leq 1%

*2 R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

*3 Not subject of production test. Verified by design/characterization.

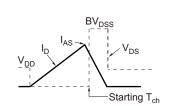


Item	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}	—	_	1	μA	V _{DS} = 40 V, V _{GS} = 0 V	
Gate Leakage Current	I _{GSS}		_	±100	nA	V_{GS} = ±20 V, V_{DS} = 0 V	
Gate to Source Threshold Voltage	V _{GS(th)}	2.0	3.0	4.0	V	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	
Forward Transfer Admittance *1	y _{fs}	60	120	_	S	V _{DS} = 5 V, I _D = 55 A	
Drain to Source On-state Resistance *1	R _{DS(on)}		1.15	1.40	mΩ	V _{GS} = 10 V, I _D = 55 A	
Input Capacitance *2	Ciss		10500	15750	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss		1600	2400	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	Crss		540	980	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}		38	90	ns	V _{DD} = 20 V, I _D = 55 A	
Rise Time *2	tr		21	60	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}		140	280	ns	R _G = 0 Ω	
Fall Time *2	t _f		20	50	ns		
Total Gate Charge *2	Q _G		198	297	nC	V _{DD} = 32 V	
Gate to Source Charge	Q _{GS}		50	_	nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}		48	—	nC	I _D = 110 A	
Body Diode Forward Voltage *1	VF(S-D)	_	0.9	1.5	V	I _F = 110 A, V _{GS} = 0 V	
Reverse Recovery Time	trr		83		ns	I _F = 110 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr		130	—	nC	di/dt = 100 A/μs	

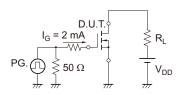
Note: *1 Pulsed test

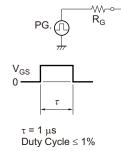
Note: *2 Not subject of production test. Verified by design/characterization.

TEST CIRCUIT 1 AVALANCHE CAPABILITY



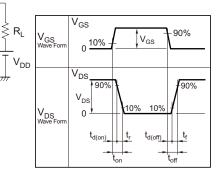
TEST CIRCUIT 3 GATE CHARGE





TEST CIRCUIT 2 SWITCHING TIME

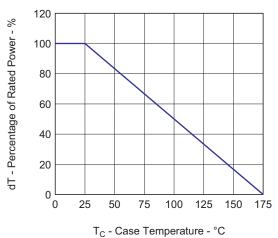
D.U.T.

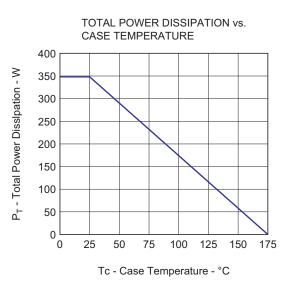




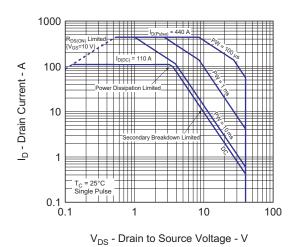
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

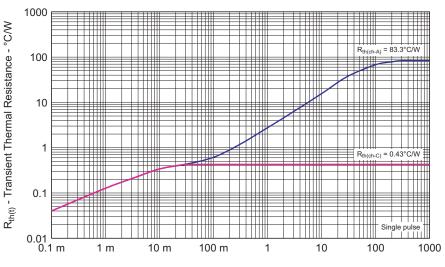




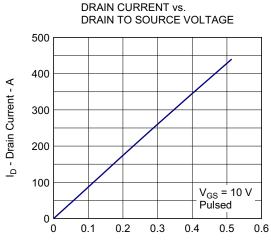
FORWARD BIAS SAFE OPERATING AREA



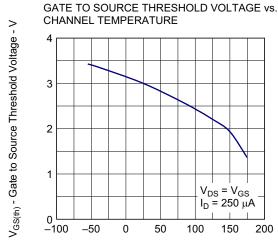




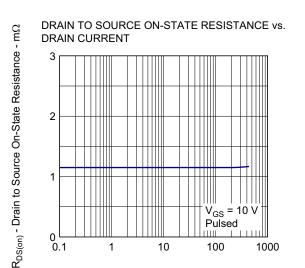




V_{DS} - Drain to Source Voltage - V



T_{ch} - Channel Temperature - °C



I_D - Drain Current - A

1000

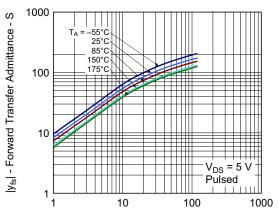
100

25°C 85°C l_D - Drain Curent - A 10 150°C 1 0.1 0.01 V_{DS} = 10 V Ξ Pulsed 0.001 0 2 3 5 6 1 4

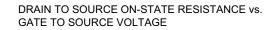
55°C

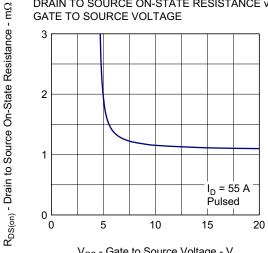
V_{GS} - Gate to Source Voltage - V

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



I_D - Drain Current - A

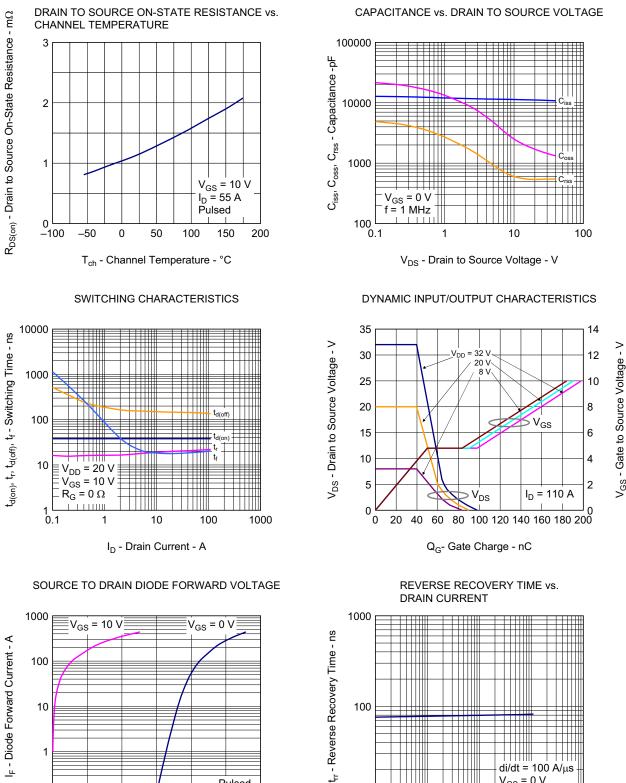




V_{GS} - Gate to Source Voltage - V

FORWARD TRANSFER CHARACTERISTICS

NP110N04PUK



10

1

0.1 0

0.2

0.4

0.6

 $V_{F(S-D)}$ - Source to Drain Voltage - V

0.8

Pulsed

1.2

1.0

1

10 └ 0.1

di/dt = 100 A/µs V_{GS} = 0 V

100

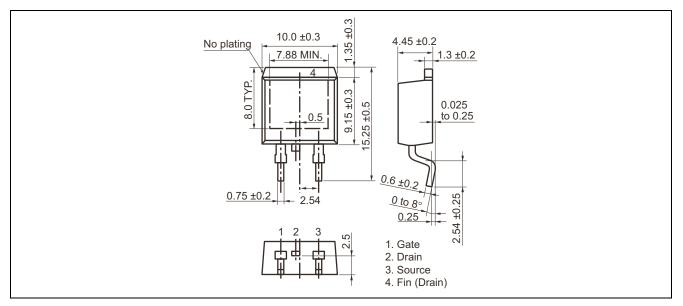
1000

10

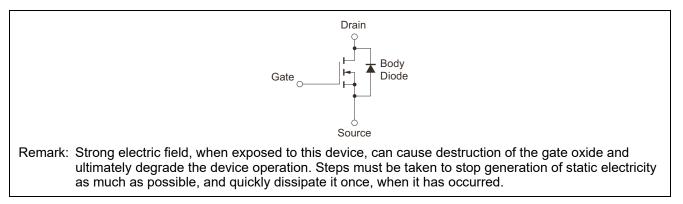
IF - Drain Current - A

Package Drawing (Unit: mm)

TO-263 (MP-25ZP) (Mass: 1.5 g TYP.)



Equivalent Circuit





NP110N04PUK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Nov 17, 2011	—	First Edition Issued	
2.00	May 24 ,2018	1	Note 3 was added	
		2	Note 2 was added	

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